

10A 200V

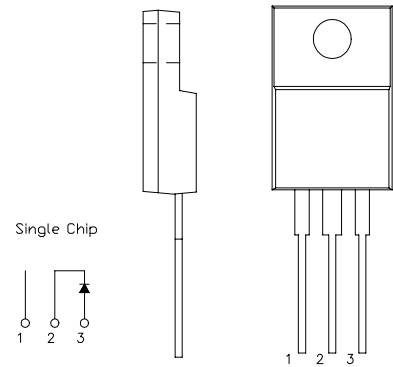
SBD Type : **FSH10A20B**

OUTLINE DRAWING

For High Frequency Rectification

FEATURES

- * High VRM SBD
- * Low Forward Voltage Drop and Low Noise
- * Fully Molded Isolation



Maximum Ratings

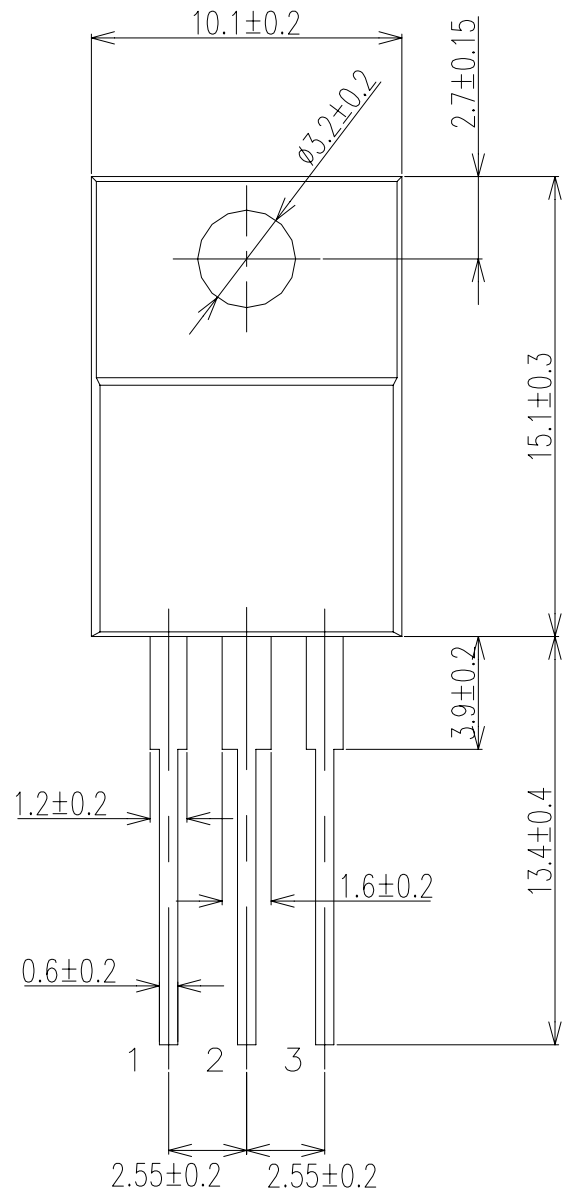
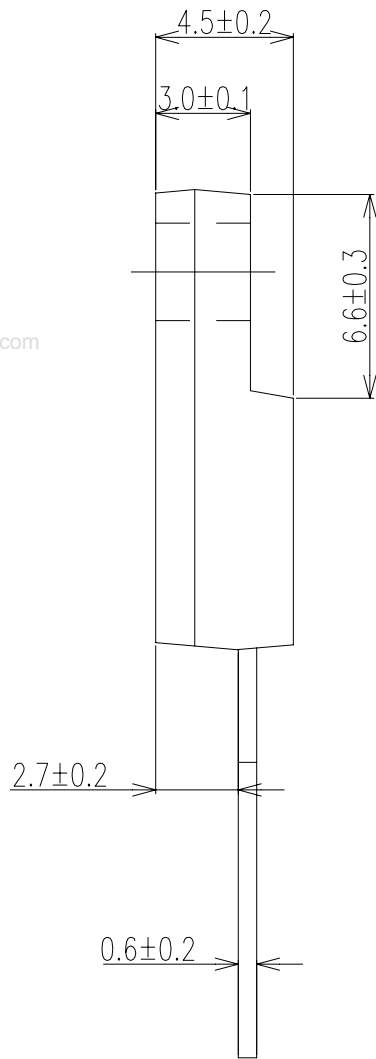
Approx Net Weight:1.75g

Rating	Symbol	FSH10A20B			Unit
Repetitive Peak Reverse Voltage	V _{RRM}	200			V
Average Rectified Output Current	I _O	10	Tc=108℃	50 Hz,Half Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	15.7			A
Surge Forward Current	I _{FSM}	120	50 Hz Half Sine Wave,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T _{jw}	- 40 to + 150			℃
Storage Temperature Range	T _{stg}	- 40 to + 150			℃
Mounting torque		0.5	Recommended value		N•m

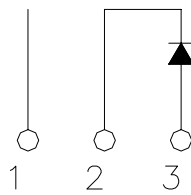
Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j=25^{\circ}\text{C}, V_{RM}=V_{RRM}$	-	-	200	μA
Peak Forward Voltage	V_{FM}	$T_j=25^{\circ}\text{C}, I_{FM}=10\text{A}$	-	-	0.90	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	3	$^{\circ}\text{C/W}$
	$R_{th(c-f)}$	Case to Fin	-	-	1.5	

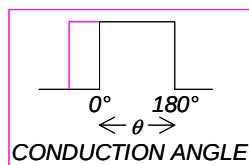
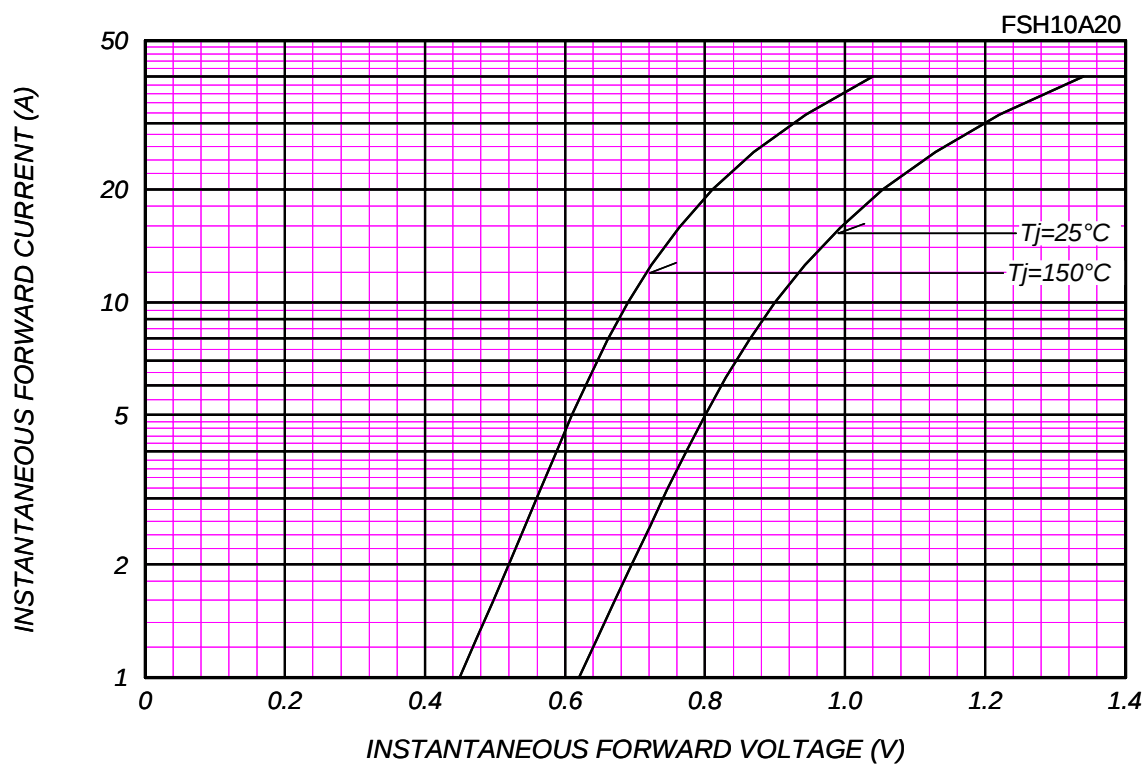
FSH_A_B OUTLINE DRAWING (Dimensions in mm)



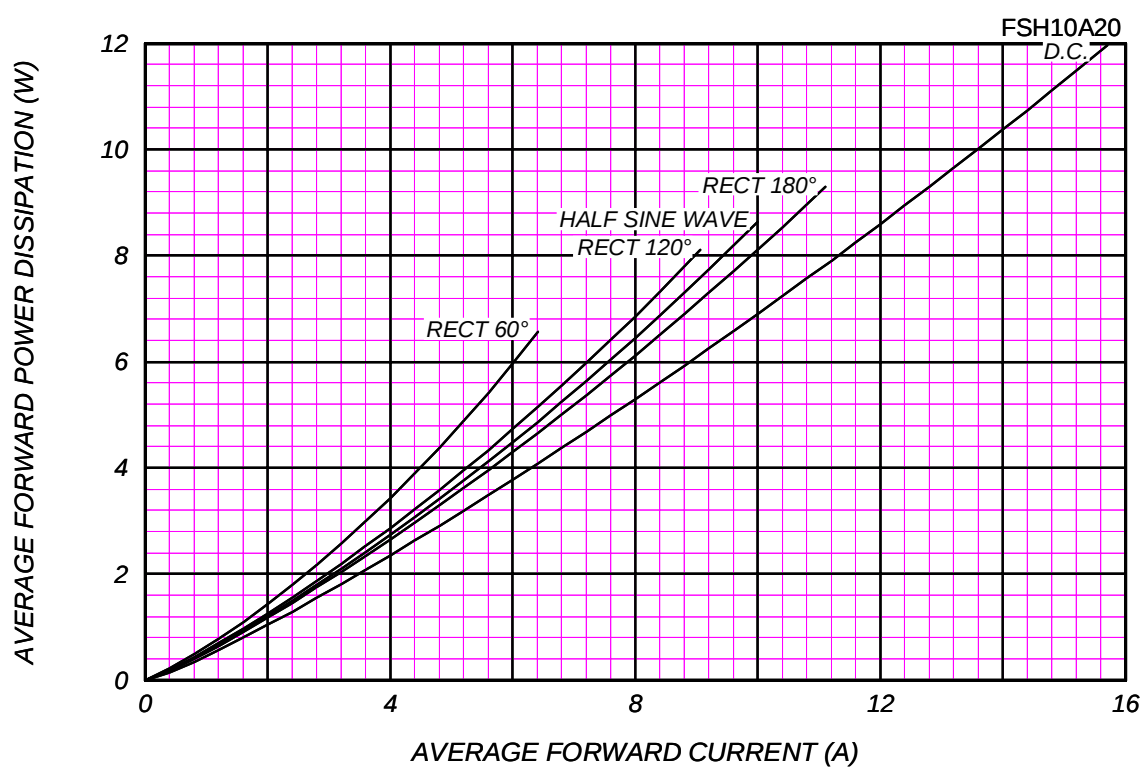
Single Chip



FORWARD CURRENT VS. VOLTAGE



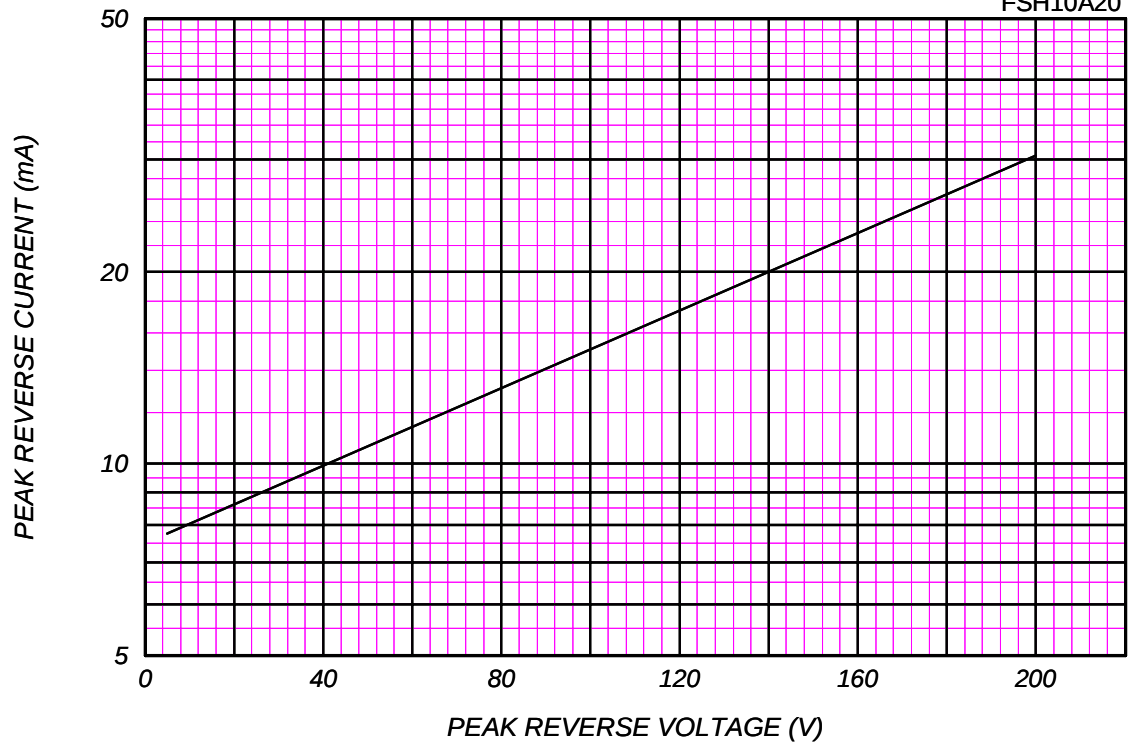
AVERAGE FORWARD POWER DISSIPATION



PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

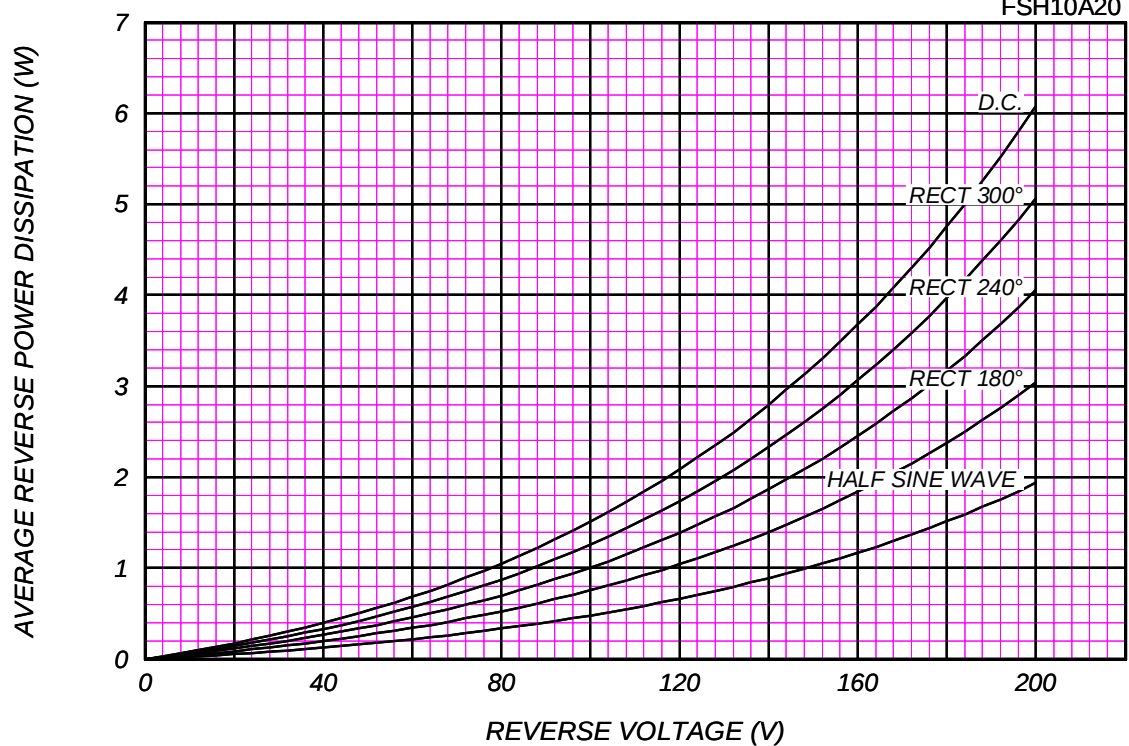
$T_j = 150\text{ }^{\circ}\text{C}$

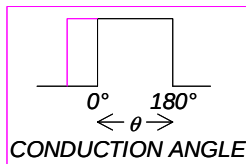
FSH10A20



AVERAGE REVERSE POWER DISSIPATION

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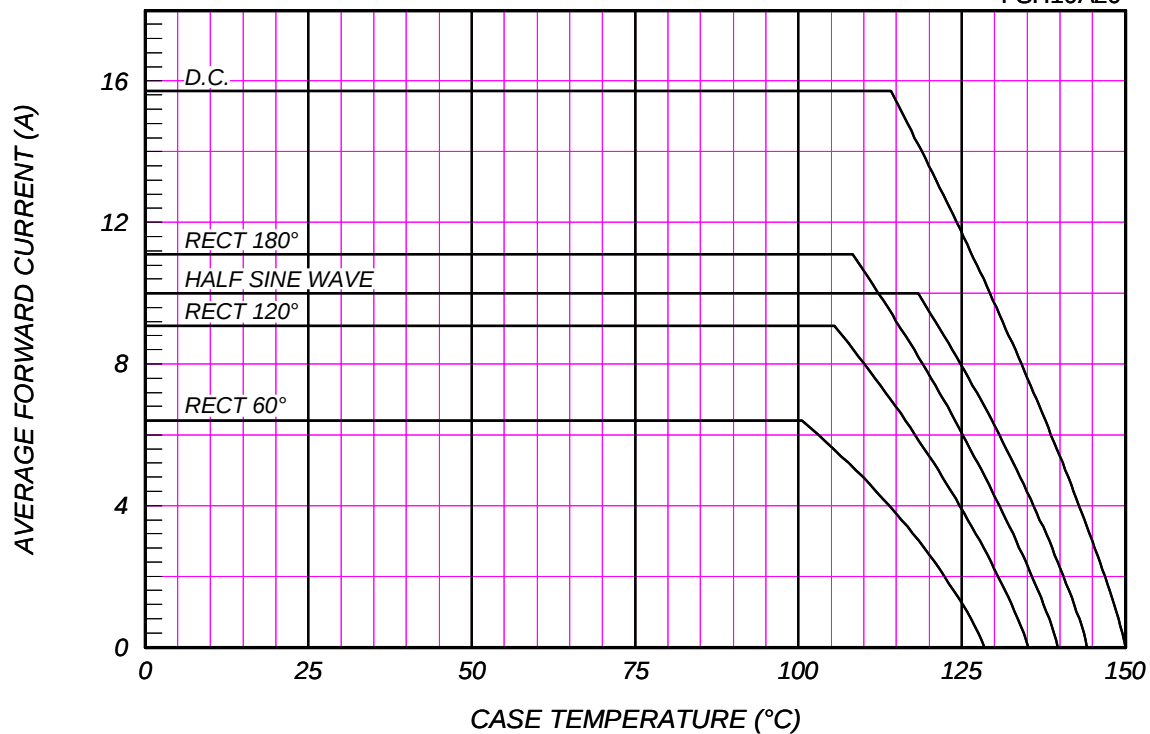




AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM}=200V$

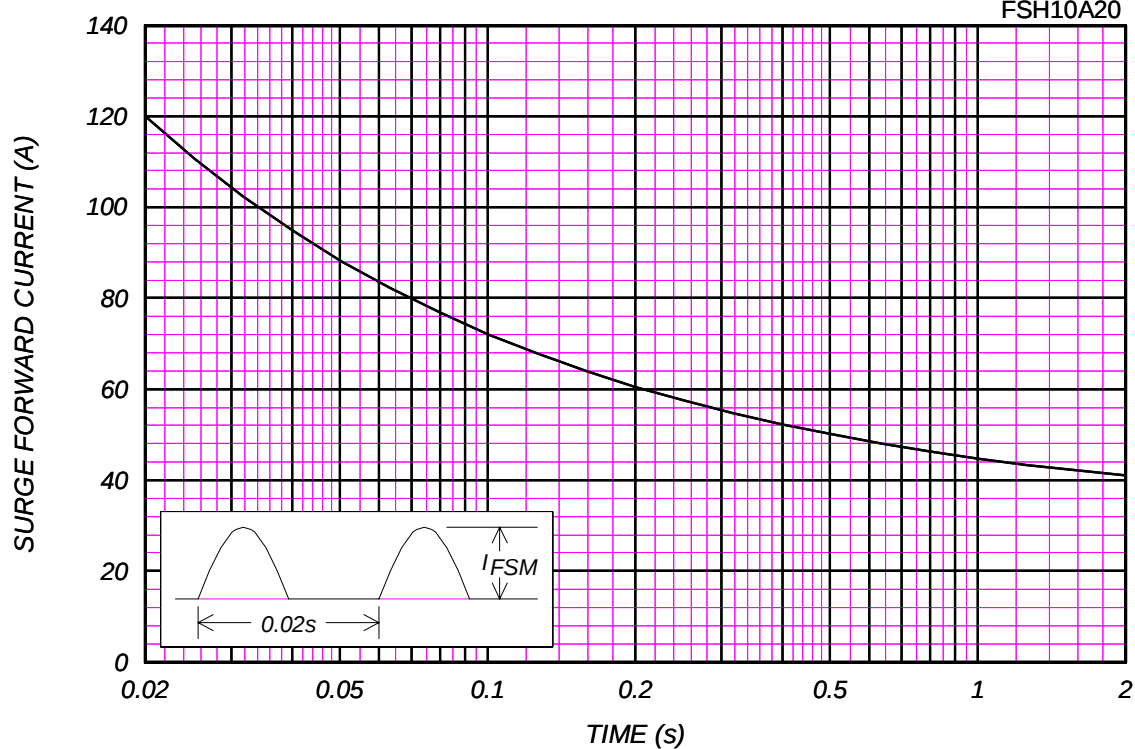
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SURGE CURRENT RATINGS

$f=50Hz$, Half Sine Wave, Non-Repetitive, No Load

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JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

$T_j=25^{\circ}\text{C}$, $V_m=20\text{mV}_{\text{RMS}}$, $f=100\text{kHz}$, Typical Value

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